

Switchmode Full Plastic Single Ultra-fast Power Rectifiers

Designed for use in switching power supplies, inverters and as free wheeling diodes. These state-of-the-art devices have the following features:

- * Low T_{RR}
- * High Surge Capacity
- * Low Power Loss, High efficiency
- * 175 Operating Junction Temperature
- * Low Forward Voltage, High Frequency
- * High-Switching Speed 21(typ.) Nanosecond Recovery Time
- * Plastic Material used Carries Underwriters Laboratory



* In compliance with EU RoHs 2002/95/EC directives

**ULTRA FAST
RECTIFIERS**

**8 AMPERES
600 VOLTS**



ITO-220AC

MAXIMUM RATINGS

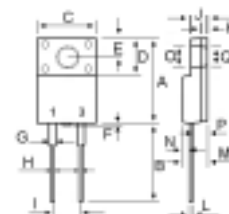
Characteristic	Symbol	UFF08A60	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	600	V
RMS Reverse Voltage	$V_{R(RMS)}$	420	V
Average Rectifier Forward Current	$I_{F(AV)}$	8.0	A
Peak Repetitive Forward Current (Rate V_R , Square Wave, 20kHz, $T_C=125^\circ\text{C}$)	I_{FM}	8.0	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-wave, single phase, 60Hz)	I_{FSM}	150	A
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +175	

THERMAL RESISTANCES

Typical Thermal Resistance junction to case	$R_{\theta jc}$	4.2	/w
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ELECTRIAL CHARACTERISTICS

Characteristic	Symbol	Min	Type	Max.	Unit
Maximum Instantaneous Forward Voltage ($I_F=8\text{ Amp } T_C=25^\circ\text{C}$)	V_F	--	1.85	2.2	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C=25^\circ\text{C}$) (Rated DC Voltage, $T_C=100^\circ\text{C}$)	I_R	--	--	25 5	μA mA
Reverse Recovery Time ($I_F=0.5\text{ A}$, $I_R=1.0$, $I_{rr}=0.25\text{ A}$)	T_{rr}	--	18	25	ns



DIM	MILLIMETERS	
	MIN	MAX
A	15.05	15.15
B	13.35	13.45
C	10.00	10.10
D	6.55	6.65
E	2.65	2.75
F		1.00
G	1.15	1.25
H	0.55	0.65
I	4.80	5.20
J	3.00	3.20
K	1.10	1.20
L	0.55	0.65
M	4.40	4.60
N	1.15	1.25
O	3.35	3.45
P	2.65	2.75
Q	3.15	3.25

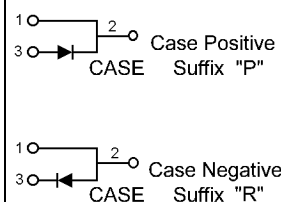


FIG-1 TYPICAL FORWARD CHARACTERISTICS

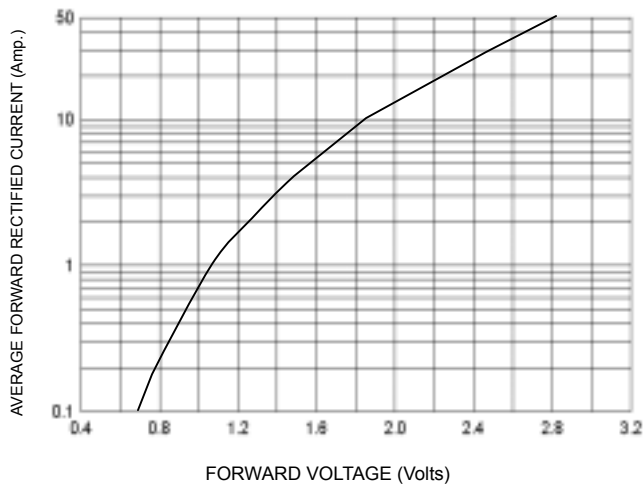


FIG-2 FORWARD CURRENT DERATING CURVE

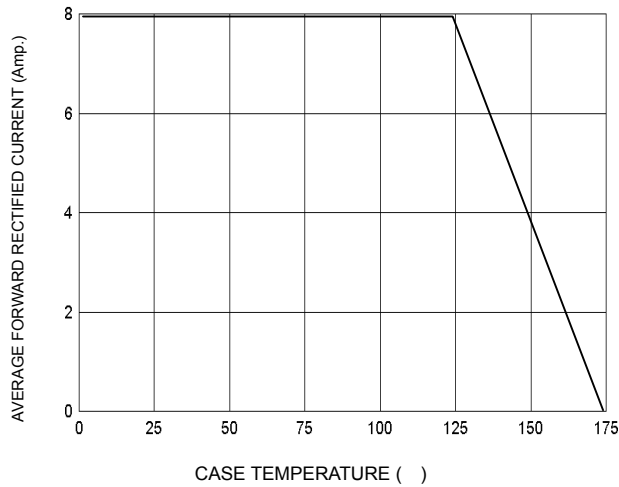


FIG-3 TYPICAL REVERSE CHARACTERISTICS

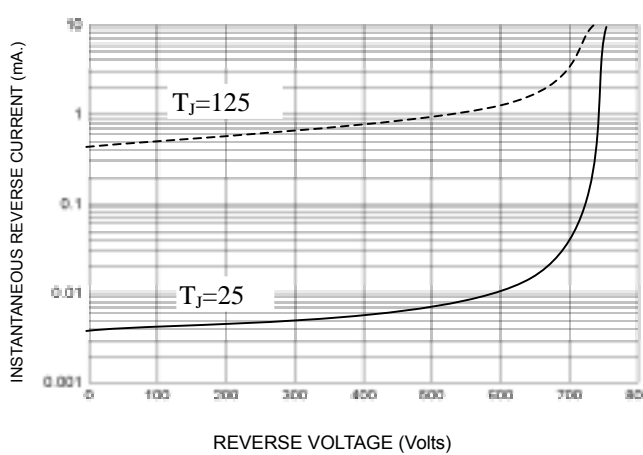
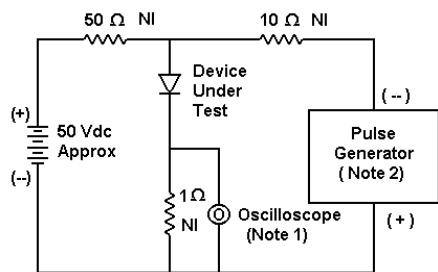
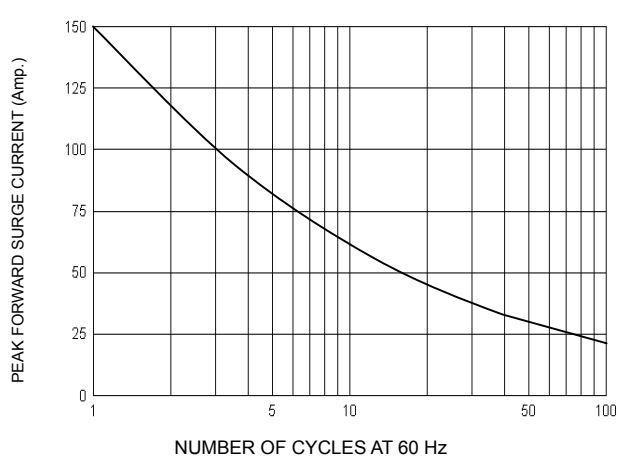
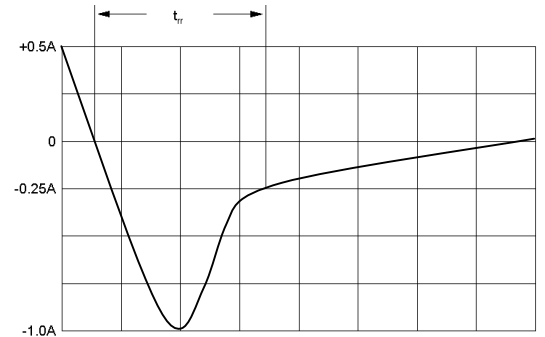


FIG-4 PEAK FORWARD SURGE CURRENT



- Notes:
1. Rise Time = 7 ns max. Input Impedance = 1 M Ω , 22 pF
 2. Rise Time = 10 ns max. Input Impedance = 50 Ω



Set time base for 10/20 ns/cm

FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram

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